

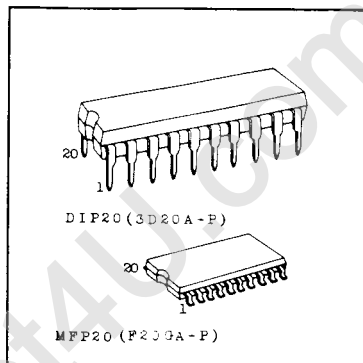
C<sup>2</sup>MOS DIGITAL INTEGRATED CIRCUIT  
SILICON MONOLITHIC

# TC40H245P/F

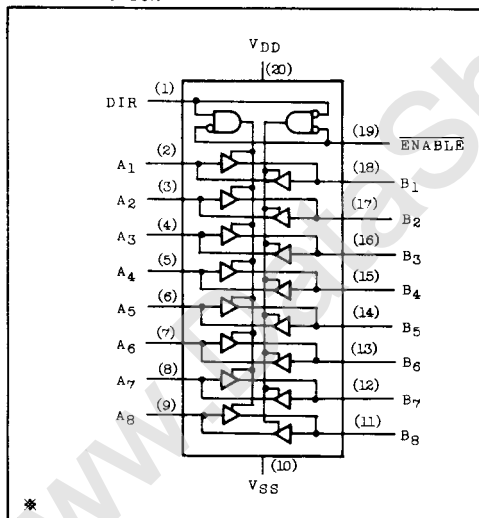
TC40H245 OCTAL BIDIRECTIONAL BUS BUFFER  
NONINVERTED 3-STATE OUTPUTS

### MAXIMUM RATINGS

CHARACTERISTIC	SYMBOL	RATING	SYMBOL
Supply Voltage	V <sub>DD</sub>	V <sub>SS</sub> -0.5 ~ V <sub>SS</sub> +10	V
Input Voltage	V <sub>IN</sub>	V <sub>SS</sub> -0.5 ~ V <sub>DD</sub> +0.5	V
Output Voltage	V <sub>OUT</sub>	V <sub>SS</sub> -0.5 ~ V <sub>DD</sub> +0.5	V
Input Current	I <sub>IN</sub>	±10	mA
Power Dissipation	P <sub>D</sub>	300 (DIP) / 180 (MFP)	mW
Storage Temperature	T <sub>stg</sub>	-65 ~ 150	°C
Lead Temp. /Time	T <sub>sol</sub>	260°C • 10 sec	



### PIN CONNECTION



### TRUTH TABLE

CONTROL INPUTS		DATA PORT STATUS
ENABLE	DIR	
L	L	B data to A bus
L	H	A data to B bus
H	X	High Impedance

X=Don't care

- TC40H245 IS A OCTAL BIDIRECTIONAL BUS BUFFER THAT HAS 3-STATE OUTPUT.
- MOST SUITABLE FOR 8-BIT DATA LINE.
- LARGE OUTPUT CURRENT CAPACITY ENABLES TO DRIVE 10 LSTTL GATE.

### RECOMMENDED OPERATING CONDITIONS (V<sub>SS</sub>=0.0V)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Voltage	V <sub>DD</sub>		2.0	-	8.0	V
Input Voltage	V <sub>IN</sub>		0	-	V <sub>DD</sub>	V
Operating Temperature	T <sub>opr</sub>		-40	-	85	°C

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ELECTRICAL CHARACTERISTICS (V<sub>SS</sub>=0.0V)

CHARACTERISTIC	SYMBOL	TEST CONDITION	V <sub>DD</sub> (V)	-40°C		25°C			85°C		UNIT
				MIN.	MAX.	MIN.	TYP.	MAX.	MIN.	MAX.	
High Level Output Voltage	V <sub>OH</sub>	I <sub>OUT</sub>   < 1μA V <sub>IN</sub> =V <sub>SS</sub> , V <sub>DD</sub>	5	4.95	-	4.95	5.0	-	4.95	-	V
Low Level Output Voltage	V <sub>OL</sub>	I <sub>OUT</sub>   < 1μA V <sub>IN</sub> =V <sub>SS</sub> , V <sub>DD</sub>	5	-	0.05	-	0.0	0.05	-	0.05	
High Level Output Current	I <sub>OH</sub>	V <sub>OH</sub> =4.6V V <sub>IN</sub> =V <sub>SS</sub> , V <sub>DD</sub>	5	-0.95	-	-0.88	-	-	-0.8	-	mA
Low Level Output Current	I <sub>OL</sub>	V <sub>OL</sub> =0.4V V <sub>IN</sub> =V <sub>SS</sub> , V <sub>DD</sub>	5	4.7	-	4.4	-	-	4.0	-	
Input Voltage	"H" Level V <sub>IH</sub>	I <sub>OUT</sub>   < 1μA V <sub>OH</sub> =4.5V V <sub>OH</sub> =0.5V	5	4.0	-	4.0	-	-	4.0	-	V
	"L" Level V <sub>IL</sub>		5	-	1.0	-	-	1.0	-	1.0	
Input Current	"H" Level I <sub>IH</sub>	V <sub>IH</sub> =8.0V	8	-	0.5	-	10 <sup>-4</sup>	0.5	-	5	μA
	"L" Level I <sub>IL</sub>	V <sub>IL</sub> =0.0V	8	-	-0.5	-	-10 <sup>-4</sup>	-0.5	-	-5	
Output Disable Current	"H" Level I <sub>DH</sub>	V <sub>DH</sub> =8.0V	8	-	0.5	-	10 <sup>-4</sup>	0.5	-	5	μA
	"L" Level I <sub>DL</sub>	V <sub>DL</sub> =0.0V	8	-	-0.5	-	-10 <sup>-4</sup>	-0.5	-	-5	
Quiescent Supply Current	I <sub>DD</sub>	*V <sub>IN</sub> =V <sub>SS</sub> , V <sub>DD</sub>	5	-	5.0	-	0.005	5.0	-	25	μA

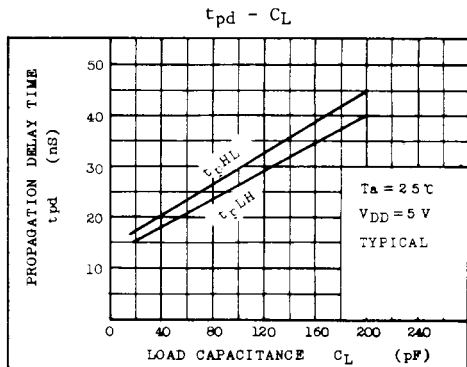
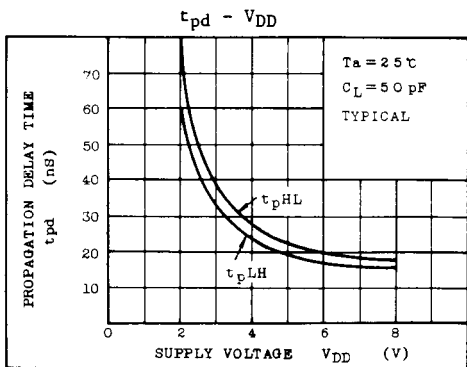
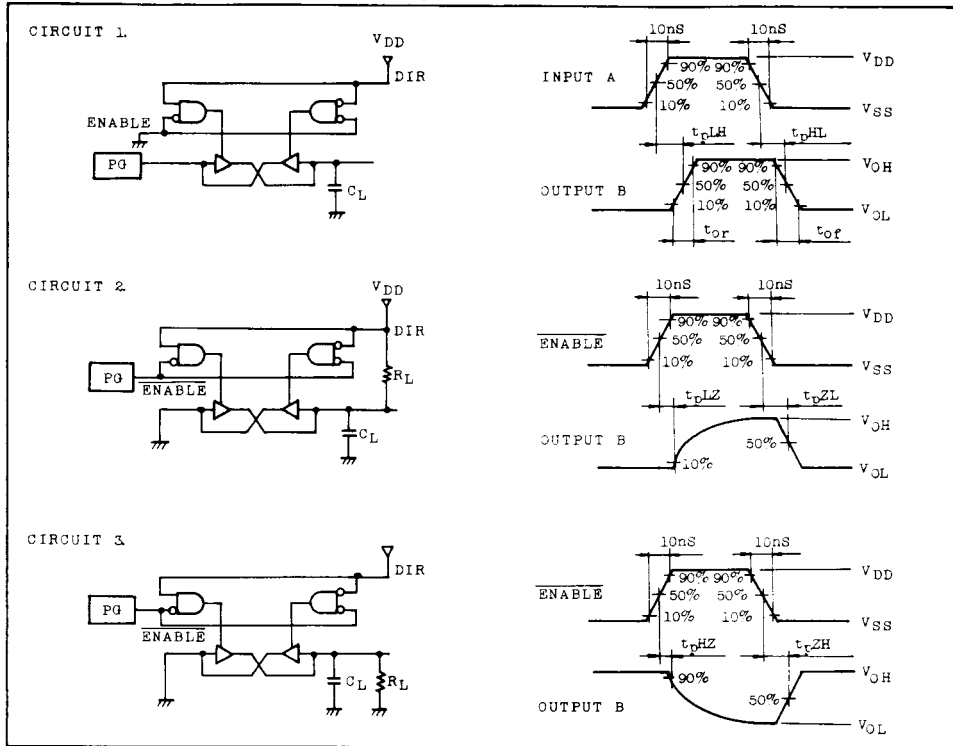
\* All valid input combinations.

SWITCHING CHARACTERISTICS (T<sub>a</sub>=25°C, V<sub>SS</sub>=0V, V<sub>DD</sub>=5V, C<sub>L</sub>=50pF, R<sub>L</sub>=1kΩ)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Rise Time	t <sub>or</sub>	Fig. 1	-	15	36	ns
Output Fall Time	t <sub>of</sub>		-	12	30	
High Level Propagation Delay Time	t <sub>pLH</sub>	Fig. 1	-	19	29	ns
Low Level Propagation Delay Time	t <sub>pHL</sub>		-	23	35	
Output Disable Time	"H" Level t <sub>pHZ</sub>	Fig. 3	-	40	60	ns
	"L" Level t <sub>pLZ</sub>	Fig. 2	-	31	47	
Output Enable Time	"H" Level t <sub>pZH</sub>	Fig. 3	-	39	60	ns
	"L" Level t <sub>pZL</sub>	Fig. 2	-	35	53	
Input Capacitance	C <sub>IN</sub>	DI, ENA	-	5		PF
Input Capacitance	C <sub>IN</sub>	A, B	-	19		

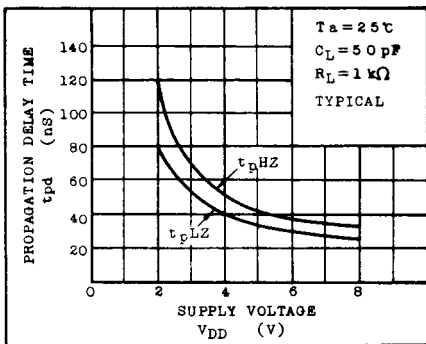
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## SWITCHING TIME TEST CIRCUIT AND WAVEFORM

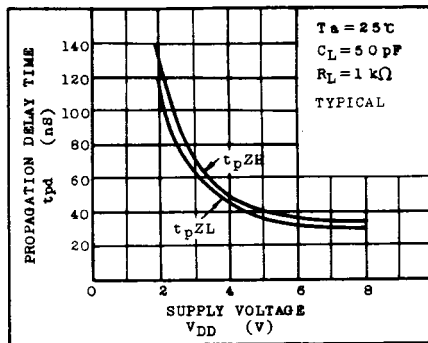


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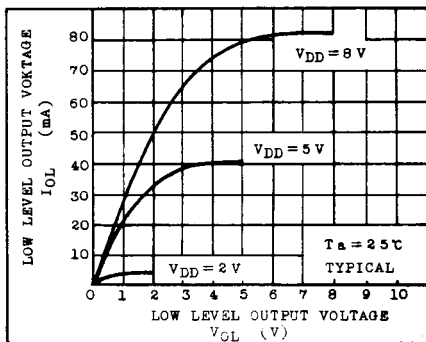
$t_{pd} - V_{DD}$



$t_{pd} - V_{DD}$



$I_{OL} - V_{OL}$



$I_{OH} - (V_{DD} - V_{OH})$

